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Data Sheet

$\pi 120U/\pi 121U/\pi 122U$

FEATURES

Ultra low power consumption (150Kbps):

0.55mA/Channel

High data rate: $\pi 12xAxx$: 600Mbps
 $\pi 12xExx$: 200Mbps
 $\pi 12xMxx$: 10Mbps
 $\pi 12xUxx$: 150kbps

High common-mode transient immunity: 150 kV/ μ s typical

High robustness to radiated and conducted noise

Isolation voltages:

$\pi 12xx3x$: AC 3000Vrms

$\pi 12xx6x$: AC 6000Vrms

High ESD rating:

ESDA/JEDEC JS-001-2017

Human body model (HBM) ± 8 kV, all pins

Safety and regulatory approvals (Pending):

UL certificate number: E494497

3000Vrms/6000Vrms for 1 minute per UL 1577

CSA Component Acceptance Notice 5A

VDE certificate number: 40047929

DIN V VDE V 0884-10 (VDE V 0884-10):2006-12

$V_{IORM} = 707V$ peak/1200V peak

CQC certification per GB4943.1-2011

3 V to 5.5 V level translation

Wide temperature range: $-40^{\circ}C$ to $125^{\circ}C$

8/16-lead, RoHS-compliant, (W)SOIC package

APPLICATIONS

General-purpose multichannel isolation

Industrial field bus isolation

GENERAL DESCRIPTION

The $\pi 1xxxx$ is a 2PaiSemi digital isolators product family that includes over hundreds of digital isolator products. By using matured standard semiconductor CMOS technology and 2PaiSEMI *iDivider* technology, these isolation components provide outstanding performance characteristics and reliability superior to alternatives such as optocoupler devices and other integrated isolators.

Intelligent voltage divider technology (*iDivider* technology) is a new generation digital isolator technology invented by 2PaiSEMI. It uses the principle of capacitor voltage divider to transmit voltage signal directly cross the isolator capacitor without signal modulation and demodulation.

The $\pi 1xxxx$ isolator data channels are independent and are available in a variety of configurations with a withstand voltage rating of 1.5 kV rms to 6.0 kV rms and the data rate from DC up

to 600Mbps (see the Ordering Guide). The devices operate with the supply voltage on either side ranging from 3.0 V to 5.5 V, providing compatibility with lower voltage systems as well as enabling voltage translation functionality across the isolation barrier. The fail-safe state is available in which the outputs transition to a preset state when the input power supply is not applied.

FUNCTIONAL BLOCK DIAGRAMS

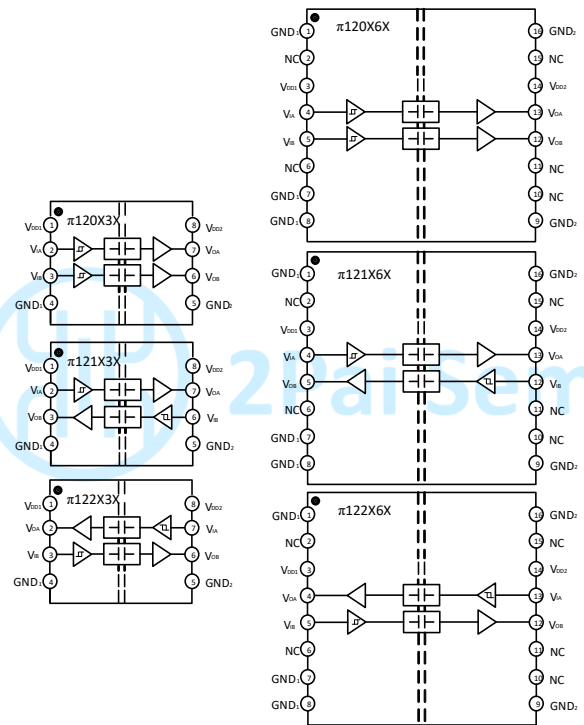


Figure1. $\pi 120xxx/\pi 121xxx/\pi 122xxx$ functional Block Diagram

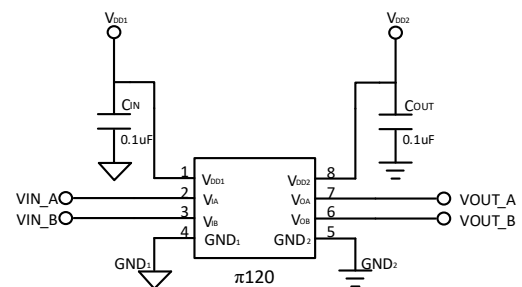


Figure2. $\pi 120xxx$ Typical Application Circuit

PIN CONFIGURATIONS AND FUNCTIONS

$\pi 120U3x$ Pin Function Descriptions

Pin No.	Name	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1.
2	V _{IA}	Logic Input A.
3	V _{IB}	Logic Input B.
4	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
5	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
6	V _{OB}	Logic Output B.
7	V _{OA}	Logic Output A.
8	V _{DD2}	Supply Voltage for Isolator Side 2.

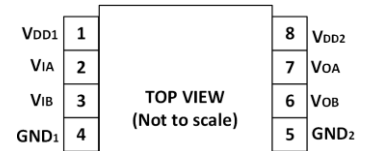


Figure3. $\pi 120U3x$ Pin Configuration

$\pi 121U3x$ Pin Function Descriptions

Pin No.	Name	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1.
2	V _{IA}	Logic Input A.
3	V _{OB}	Logic Output B.
4	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
5	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
6	V _{IB}	Logic Input B.
7	V _{OA}	Logic Output A.
8	V _{DD2}	Supply Voltage for Isolator Side 2.

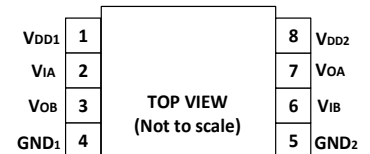


Figure4. $\pi 121U3x$ Pin Configuration

$\pi 122U3x$ Pin Function Descriptions

Pin No.	Name	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1.
2	V _{OA}	Logic Output A.
3	V _{IB}	Logic Input B.
4	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
5	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
6	V _{OB}	Logic Output B.
7	V _{IA}	Logic Input A.
8	V _{DD2}	Supply Voltage for Isolator Side 2.

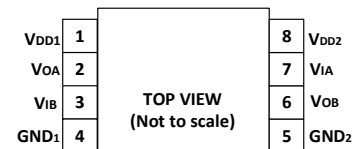


Figure5. $\pi 122U3x$ Pin Configuration

$\pi 120U6x$ Pin Function Descriptions

Pin No.	Name	Description
1	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
2	NC	No connect.
3	V _{DD1}	Supply Voltage for Isolator Side 1.
4	V _{IA}	Logic Input A.
5	V _{IB}	Logic Input B.
6	NC	No Connect.
7	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
8	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
9	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

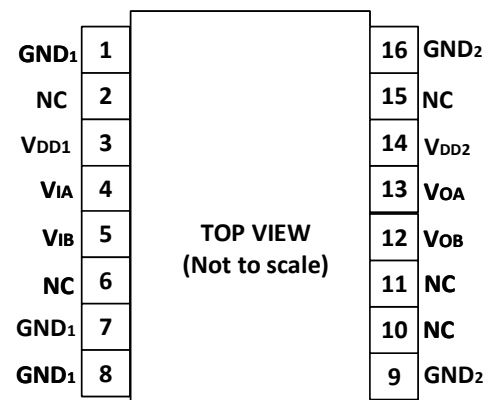
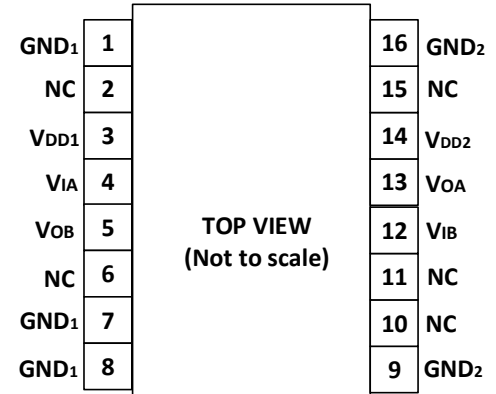


Figure6. $\pi 120U6x$ Pin Configuration

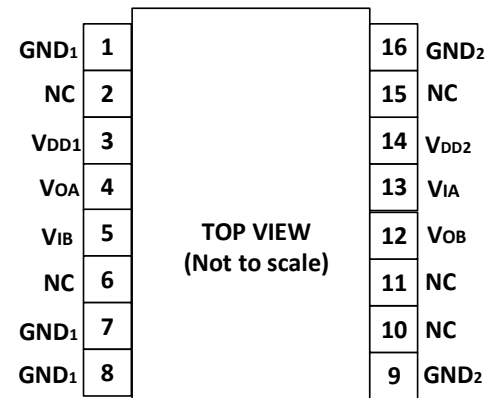
10	NC	No Connect.
11	NC	No Connect.
12	V _{OB}	Logic Output B.
13	V _{OA}	Logic Output A.
14	V _{DD2}	Supply Voltage for Isolator Side 2.
15	NC	No Connect.
16	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

 $\pi 121U6x$ Pin Function Descriptions

Pin No.	Name	Description
1	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
2	NC	No Connect.
3	V _{DD1}	Supply Voltage for Isolator Side 1.
4	V _{IA}	Logic Input A.
5	V _{OB}	Logic Output B.
6	NC	No Connect.
7	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
8	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
9	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
10	NC	No Connect.
11	NC	No Connect.
12	V _{IB}	Logic Input B.
13	V _{OA}	Logic Output A.
14	V _{DD2}	Supply Voltage for Isolator Side 2.
15	NC	No Connect.
16	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

Figure7. $\pi 121U6x$ Pin Configuration $\pi 122U6x$ Pin Function Descriptions

Pin No.	Name	Description
1	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
2	NC	No Connect.
3	V _{DD1}	Supply Voltage for Isolator Side 1.
4	V _{OA}	Logic Output A.
5	V _{IB}	Logic Input B.
6	NC	No Connect.
7	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
8	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
9	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
10	NC	No Connect.
11	NC	No Connect.
12	V _{OB}	Logic Output B.
13	V _{IA}	Logic Input A.
14	V _{DD2}	Supply Voltage for Isolator Side 2.
15	NC	No Connect.
16	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

Figure8. $\pi 122U6x$ Pin Configuration

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 1. Absolute Maximum Ratings⁴

Parameter	Rating
Supply Voltages ($V_{DD1}\text{-GND}_1$, $V_{DD2}\text{-GND}_2$)	-0.5 V to +7.0 V
Input Voltages (V_{IA} , V_{IB}) ¹	-0.5 V to $V_{DDx} + 0.5$ V
Output Voltages (V_{OA} , V_{OB}) ¹	-0.5 V to $V_{DDx} + 0.5$ V
Average Output Current per Pin ² Side 1 Output Current (I_{O1})	-10 mA to +10 mA
Average Output Current per Pin ² Side 2 Output Current (I_{O2})	-10 mA to +10 mA
Common-Mode Transients Immunity ³	-150 kV/ μs to +150 kV/ μs
Storage Temperature (T_{ST}) Range	-65°C to +150°C
Ambient Operating Temperature (T_A) Range	-40°C to +125°C

Notes:

¹ V_{DDx} is the side voltage power supply V_{DD} , where x = 1 or 2.

² See Figure9 for the maximum rated current values for various temperatures.

³ See Figure18 for Common-mode transient immunity (CMTI) measurement.

⁴ Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

RECOMMENDED OPERATING CONDITIONS

Table 2. Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{DDx} ¹	3		5.5	V
High Level Input Signal Voltage	V_{IH}	$0.7 \cdot V_{DDx}$ ¹		V_{DDx} ¹	V
Low Level Input Signal Voltage	V_{IL}	0		$0.3 \cdot V_{DDx}$ ¹	V
High Level Output Current	I_{OH}	-6			mA
Low Level Output Current	I_{OL}			6	mA
Maximum Data Rate		0		150	Kbps
Junction Temperature	T_J	-40		150	°C
Ambient Operating Temperature	T_A	-40		125	°C

Notes:

¹ V_{DDx} is the side voltage power supply V_{DD} , where x = 1 or 2.

Truth Tables

Table 3. $\pi 120\text{xxx}/\pi 121\text{xxx}/\pi 122\text{xxx}$ Truth Table

V_{IX} Input ¹	V_{DDI} State ¹	V_{DDO} State ¹	Default Low V_{OX} Output ¹	Default High V_{OX} Output ¹	Test Conditions /Comments
Low	Powered ²	Powered ²	Low	Low	Normal operation
High	Powered ²	Powered ²	High	High	Normal operation
Open	Powered ²	Powered ²	Low	High	Default output
Don't Care ⁴	Unpowered ³	Powered ²	Low	High	Default output ⁵
Don't Care ⁴	Powered ²	Unpowered ³	High Impedance	High Impedance	

Notes:

¹ V_{IX}/V_{OX} are the input/output signals of a given channel (A or B). V_{DDI}/V_{DDO} are the supply voltages on the input/output signal sides of this given channel.

² Powered means $V_{DDx} \geq 2.9V$

³ Unpowered means $V_{DDx} < 2.3V$

⁴ Input signal (V_{ix}) must be in a low state to avoid powering the given V_{DDi}^1 through its ESD protection circuitry.

⁵ If the V_{DDi} goes into unpowered status, the channel outputs the default logic signal after around 1us. If the V_{DDi} goes into powered status, the channel outputs the input status logic signal after around 3us.

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS

Table 4. Switching Specifications

$V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, unless otherwise noted.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
Minimum Pulse Width	PW			6.5	us	Within pulse width distortion (PWD) limit
Maximum Data Rate		150			Kbps	Within PWD limit
Propagation Delay Time ^{1,4}	t_{pHL}, t_{pLH}		3.0	4.5	us	The different time between 50% input signal to 50% output signal 50% @ $5V_{DC}$ supply
			3.2	4.8	us	@ $3.3V_{DC}$ supply
Pulse Width Distortion ⁴	PWD	0	0.02	0.2	us	The max different time between t_{pHL} and t_{pLH} @ $5V_{DC}$ supply. And The value is $ t_{pHL} - t_{pLH} $
		0	0.02	0.2	us	@ $3.3V_{DC}$ supply
Part to Part Propagation Delay Skew ⁴	t_{PSK}			0.3	us	The max different propagation delay time between any two devices at the same temperature, load and voltage @ $5V_{DC}$ supply
				0.3	us	@ $3.3V_{DC}$ supply
Channel to Channel Propagation Delay Skew ⁴	t_{CSK}		0	0.2	us	The max amount propagation delay time differs between any two output channels in the single device @ $5V_{DC}$ supply.
			0	0.2	us	@ $3.3V_{DC}$ supply
Output Signal Rise/Fall Time ⁴	t_r/t_f		1.5		ns	10% to 90% signal terminated 50Ω , See figure15.
Common-Mode Transient Immunity ³	CMTI	100	150		kV/ μs	$V_{IN} = V_{DDx}^2$ or 0V, $V_{CM} = 1000V$.
ESD (HBM - Human body model)	ESD		± 8		kV	All pins

Notes:

¹ t_{pLH} = low-to-high propagation delay time, t_{pHL} = high-to-low propagation delay time. See figure 16.

² V_{DDx} is the side voltage power supply V_{DD} , where $x = 1$ or 2 .

³ See Figure18 for Common-mode transient immunity (CMTI) measurement.

⁴ Output Signal Terminated 50Ω .

Table 5. DC Specifications

$V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, unless otherwise noted.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
Rising Input Signal Voltage Threshold	V_{IT+}		$0.6 * V_{DDx}^1$	$0.7 * V_{DDx}^1$	V	
Falling Input Signal Voltage Threshold	V_{IT-}	$0.3 * V_{DDx}^1$	$0.4 * V_{DDx}^1$		V	
High Level Output Voltage	V_{OH}^1	$V_{DDx} - 0.1$	V_{DDx}		V	-20 μA output current
		$V_{DDx} - 0.2$	$V_{DDx} - 0.1$		V	-2 mA output current
Low Level Output Voltage	V_{OL}		0	0.1	V	20 μA output current

Input Current per Signal Channel	I_{IN}	-10	0.1	0.2	V	2 mA output current
V_{DDx}^1 Undervoltage Rising Threshold	V_{DDxUV+}	2.45	0.5	10	μA	$0V \leq \text{Signal voltage} \leq V_{DDx}^1$
V_{DDx}^1 Undervoltage Falling Threshold	V_{DDxUV-}	2.3	2.65	2.9	V	
V_{DDx}^1 Hysteresis	V_{DDxUVH}		2.5	2.75	V	
			0.15		V	

Notes:

¹ V_{DDx} is the side voltage power supply V_{DD} , where x = 1 or 2.**Table 6. Quiescent Supply Current** $V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, $C_L = 0$ pF, unless otherwise noted.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
$\pi 120U_{xx}$ Quiescent Supply Current @ $5V_{DC}$ Supply	$I_{DD1}(Q)$	154	192	250	μA	0V Input signal
	$I_{DD2}(Q)$	708	885	1151	μA	0V Input signal
	$I_{DD1}(Q)$	61	76	99	μA	5V Input signal
	$I_{DD2}(Q)$	767	959	1247	μA	5V Input signal
	@ $3.3V_{DC}$ Supply					
	$I_{DD1}(Q)$	113	141	183	μA	0V Input signal
	$I_{DD2}(Q)$	696	870	1131	μA	0V Input signal
	$I_{DD1}(Q)$	60	75	98	μA	3.3V Input signal
$\pi 121U_{xx}$ Quiescent Supply Current @ $5V_{DC}$ Supply	$I_{DD2}(Q)$	758	948	1232	μA	3.3V Input signal
	$I_{DD1}(Q)$	431	539	700	μA	0V Input signal
	$I_{DD2}(Q)$	431	539	701	μA	0V Input signal
	$I_{DD1}(Q)$	414	518	673	μA	5V Input signal
	$I_{DD2}(Q)$	414	518	673	μA	5V Input signal
	@ $3.3V_{DC}$ Supply					
	$I_{DD1}(Q)$	404	506	657	μA	0V Input signal
	$I_{DD2}(Q)$	405	506	658	μA	0V Input signal
$\pi 122U_{xx}$ Quiescent Supply Current @ $5V_{DC}$ Supply	$I_{DD1}(Q)$	409	512	665	μA	3.3V Input signal
	$I_{DD2}(Q)$	410	512	666	μA	3.3V Input signal
	$I_{DD1}(Q)$	431	539	701	μA	0V Input signal
	$I_{DD2}(Q)$	431	539	701	μA	0V Input signal
	$I_{DD1}(Q)$	414	518	673	μA	5V Input signal
	$I_{DD2}(Q)$	414	518	673	μA	5V Input signal
	@ $3.3V_{DC}$ Supply					
	$I_{DD1}(Q)$	405	506	658	μA	0V Input signal
$\pi 122U_{xx}$ Quiescent Supply Current @ $5V_{DC}$ Supply	$I_{DD2}(Q)$	405	506	658	μA	0V Input signal
	$I_{DD1}(Q)$	410	512	666	μA	3.3V Input signal
	$I_{DD2}(Q)$	410	512	666	μA	3.3V Input signal

Table 7. Total Supply Current vs. Data Throughput ($C_L = 0$ pF) $V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, $C_L = 0$ pF, unless otherwise noted.

Parameter	Symbol	2 Kbps			50Kbps			150Kbps			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$\pi 120U_{xx}$ Supply Current @ $5V_{DC}$	I_{DD1}	0.13	0.20		0.13	0.20		0.13	0.20		mA
	I_{DD2}	0.92	1.38		0.93	1.40		0.94	1.41		mA
@ $3.3V_{DC}$	I_{DD1}	0.10	0.15		0.10	0.15		0.10	0.15		mA

	I _{DD2}	0.91	1.37	0.91	1.37	0.92	1.38	mA
$\pi 121U_{xx}$ Supply Current @ 5V _{DC} @ 3.3V _{DC}	I _{DD1}	0.53	0.79	0.53	0.80	0.54	0.80	mA
	I _{DD2}	0.53	0.80	0.53	0.80	0.54	0.81	mA
	I _{DD1}	0.51	0.76	0.51	0.77	0.51	0.77	mA
	I _{DD2}	0.51	0.77	0.51	0.77	0.51	0.77	mA
$\pi 122U_{xx}$ Supply Current @ 5V _{DC} @ 3.3V _{DC}	I _{DD1}	0.53	0.80	0.53	0.80	0.54	0.81	mA
	I _{DD2}	0.53	0.80	0.53	0.80	0.54	0.81	mA
	I _{DD1}	0.51	0.77	0.51	0.77	0.51	0.77	mA
	I _{DD2}	0.51	0.77	0.51	0.77	0.51	0.77	mA

INSULATION AND SAFETY RELATED SPECIFICATIONS**Table 8. Insulation Specifications**

Parameter	Symbol	Value		Unit	Test Conditions/Comments
		$\pi 12xU3x$	$\pi 12xU6x$		
Rated Dielectric Insulation Voltage		3000	6000	V rms	1-minute duration
Minimum External Air Gap (Clearance)	L (CLR)	4	8	mm min	Measured from input terminals to output terminals, shortest distance through air
Minimum External Tracking (Creepage)	L (CRP)	4	8	mm min	Measured from input terminals to output terminals, shortest distance path along body
Minimum Internal Gap (Internal Clearance)		11	21	μ m min	Insulation distance through insulation
Tracking Resistance (Comparative Tracking Index)	CTI	>400	>400	V	DIN IEC 112/VDE 0303 Part 1
Material Group		II	II		Material Group (DIN VDE 0110, 1/89, Table 1)

PACKAGE CHARACTERISTICS**Table 9. Package Characteristics**

Parameter	Symbol	Typical Value		Unit	Test Conditions/Comments
		$\pi 12xU3x$	$\pi 12xU6x$		
Resistance (Input to Output) ¹	R _{I-O}	10 ⁻¹¹	10 ⁻¹¹	Ω	
Capacitance (Input to Output) ¹	C _{I-O}	0.6	0.6	pF	@1MHz
Input Capacitance ²	C _i	3	3	pF	@1MHz
IC Junction to Ambient Thermal Resistance	θ_{JA}	100	45	°C/W	Thermocouple located at center of package underside

Notes:

¹The device is considered a 2-terminal device; SOIC-8 Pin 1 - Pin 4 (WSOIC-16 Pin 1-Pin8) are shorted together as the one terminal, and SOIC-8 Pin 5 - Pin 8 (WSOIC-16 Pin 9-Pin16) are shorted together as the other terminal.²Testing from the input signal pin to ground.**REGULATORY INFORMATION**

See Table 10 and the Insulation Lifetime section for details regarding recommended maximum working voltages for specific cross isolation waveforms and insulation levels.

Table 10. Regulatory

Regulatory	$\pi 12xU3x$	$\pi 12xU6x$
UL	Recognized under UL 1577 Component Recognition Program ¹ Single Protection, 3000 V rms Isolation Voltage File (E494497)	Recognized under UL 1577 Component Recognition Program ¹ Single Protection, 6000V rms Isolation Voltage File (pending)

CSA	Approved under CSA Component Acceptance Notice 5A CSA 60950-1-07+A1+A2 and IEC 60950-1, second edition, +A1+A2: Basic insulation at 500 V rms (707 V peak) Reinforced insulation at 250 V rms (353 V peak) File (pending)	Approved under CSA Component Acceptance Notice 5A CSA 60950-1-07+A1+A2 and IEC 60950-1, second edition, +A1+A2: Basic insulation at 845 V rms (1200 V peak) Reinforced insulation at 422 V rms (600 V peak) File (pending)
VDE	DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 ² Basic insulation, $V_{IORM} = 707$ V peak, $V_{IOSM} = 4615$ V peak File (40047929)	DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 ² Basic insulation, $V_{IORM} = 1200$ V peak, $V_{IOSM} = 7000$ V peak File (pending)
CQC	Certified under CQC11-471543-2012 GB4943.1-2011 Basic insulation at 500 V rms (707 V peak) working voltage Reinforced insulation at 250 V rms (353 V peak) File (pending)	Certified under CQC11-471543-2012 GB4943.1-2011 Basic insulation at 845 V rms (1200 V peak) working voltage Reinforced insulation at 422 V rms (600 V peak) File (pending)

Notes:

¹ In accordance with UL 1577, each $\pi 120U3x/\pi 121U3x/\pi 122U3x$ is proof tested by applying an insulation test voltage ≥ 3600 V rms for 1 sec; each $\pi 120U6x/\pi 121U6x/\pi 122U6x$ is proof tested by applying an insulation test voltage ≥ 7200 V rms for 1 sec

² In accordance with DIN V VDE V 0884-10, each $\pi 120U3x/\pi 121U3x/\pi 122U3x$ is proof tested by applying an insulation test voltage ≥ 1326 V peak for 1 sec (partial discharge detection limit = 5 pC); each $\pi 120U6x/\pi 121U6x/\pi 122U6x$ is proof tested by ≥ 2250 V peak for 1 sec. The * marking branded on the component designates DIN V VDE V 0884-10 approval.

DIN V VDE V 0884-10 (VDE V 0884-10) INSULATION CHARACTERISTICS

These isolators are suitable for reinforced electrical isolation only within the safety limit data. Protective circuits ensure the maintenance of the safety data. The * marking on packages denotes DIN V VDE V 0884-10 approval.

Table 11. VDE Insulation Characteristics

Description	Test Conditions/Comments	Symbol	Characteristic		Unit
			$\pi 12xU3x$	$\pi 12xU6x$	
Installation Classification per DIN VDE 0110					
For Rated Mains Voltage ≤ 150 V rms			I to IV	I to IV	
For Rated Mains Voltage ≤ 300 V rms			I to III	I to III	
For Rated Mains Voltage ≤ 400 V rms			I to III	I to III	
Climatic Classification			40/105/21	40/105/21	
Pollution Degree per DIN VDE 0110, Table 1			2	2	
Maximum Working Insulation Voltage		V_{IORM}	707	1200	V peak
Input to Output Test Voltage, Method B1	$V_{IORM} \times 1.875 = V_{pd(m)}$, 100% production test, $t_{ini} = t_m = 1$ sec, partial discharge < 5 pC	$V_{pd(m)}$	1326	2250	V peak
Input to Output Test Voltage, Method A					
After Environmental Tests Subgroup 1	$V_{IORM} \times 1.5 = V_{pd(m)}$, $t_{ini} = 60$ sec, $t_m = 10$ sec, partial discharge < 5 pC	$V_{pd(m)}$	1061	1800	V peak
After Input and/or Safety Test Subgroup 2 and Subgroup 3	$V_{IORM} \times 1.2 = V_{pd(m)}$, $t_{ini} = 60$ sec, $t_m = 10$ sec, partial discharge < 5 pC		849	1440	V peak
Highest Allowable Overvoltage		V_{IOTM}	4200	8500	V peak

Surge Isolation Voltage Basic	Basic insulation, 1.2 μs rise time, 50 μs , 50% fall time	V_{IOSM}	4615	7000	V peak
Surge Isolation Voltage Reinforced	Reinforced insulation, 1.2 μs rise time, 50 μs , 50% fall time	V_{IOSM}			V peak
Safety Limiting Values	Maximum value allowed in the event of a failure (see Figure 9)				
Maximum Junction Temperature		T_S	150	150	$^{\circ}C$
Total Power Dissipation at 25 $^{\circ}C$		P_S	1.56	2.78	W
Insulation Resistance at T_S	$V_{IO} = 800\text{ V}$	R_S	$>10^9$	$>10^9$	Ω

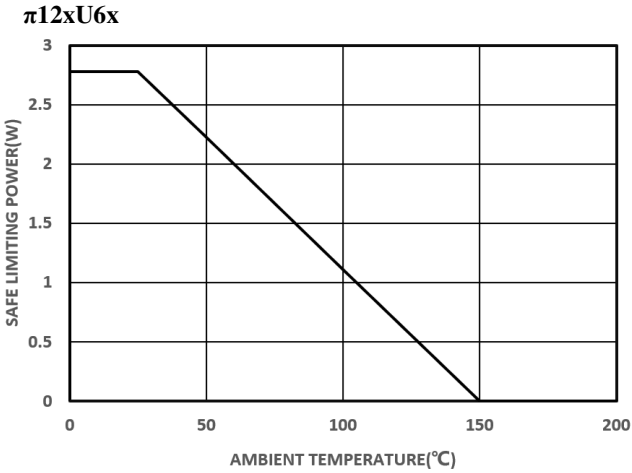
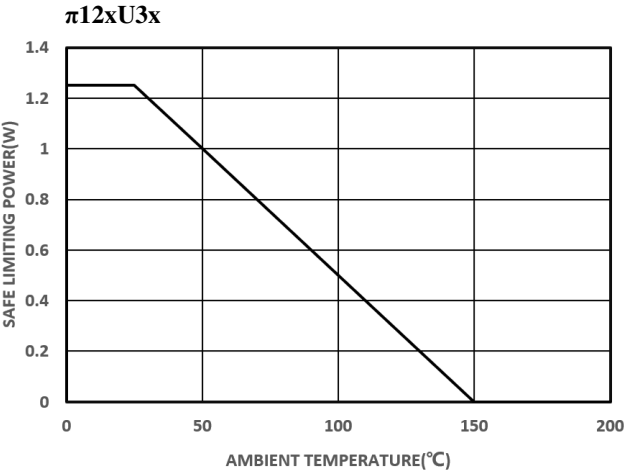


Figure9. Thermal Derating Curve, Dependence of Safety Limiting Values with Ambient Temperature per VDE

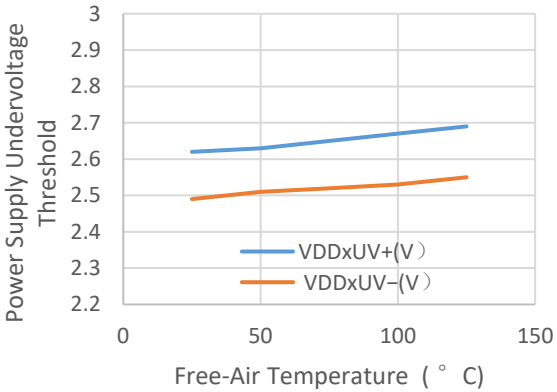


Figure10. UVLO vs. Free-Air Temperature

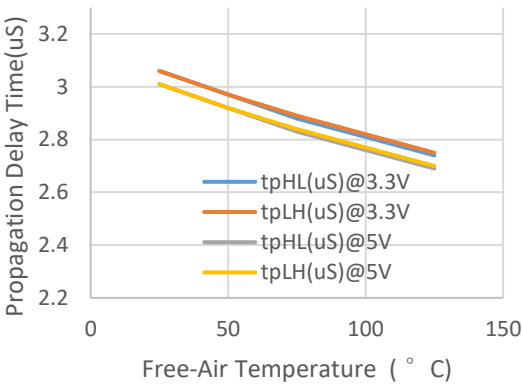


Figure11. Propagation Delay Time vs. Free-Air Temperature

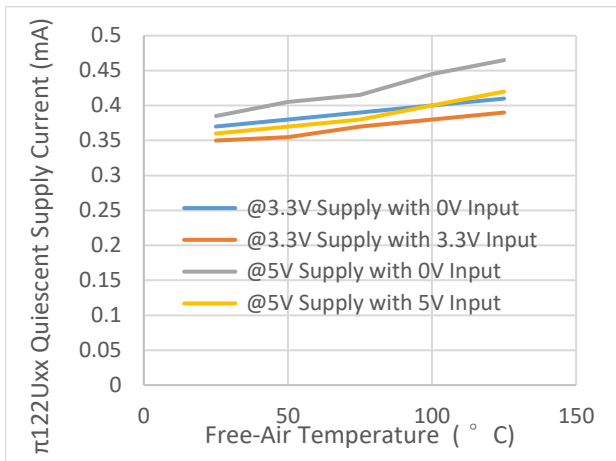


Figure12. $\pi 121\text{Uxx}/\pi 122\text{Uxx}$ Quiescent Supply Current vs. Free-Air Temperature

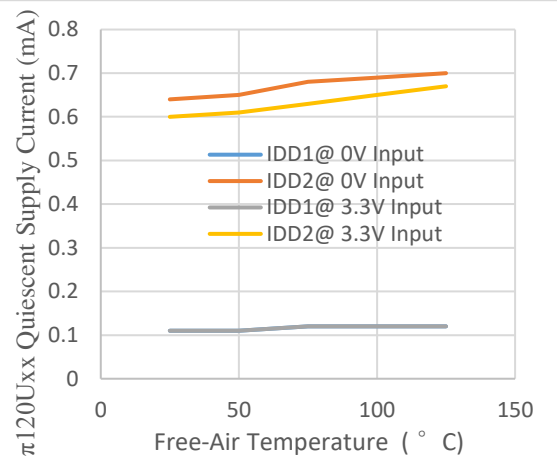


Figure13. $\pi 120\text{Uxx}$ Quiescent Supply Current with 3.3V Supply vs. Free-Air Temperature

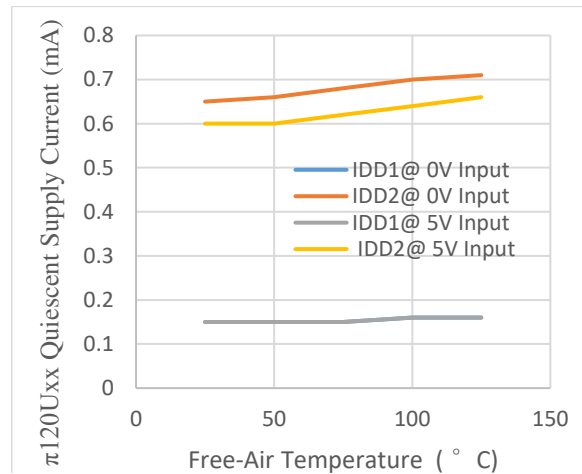


Figure14. $\pi 120\text{Uxx}$ Quiescent Supply Current with 5V Supply vs. Free-Air Temperature

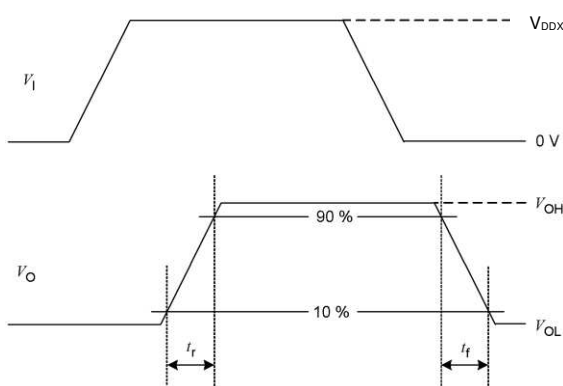


Figure15. Transition time waveform measurement

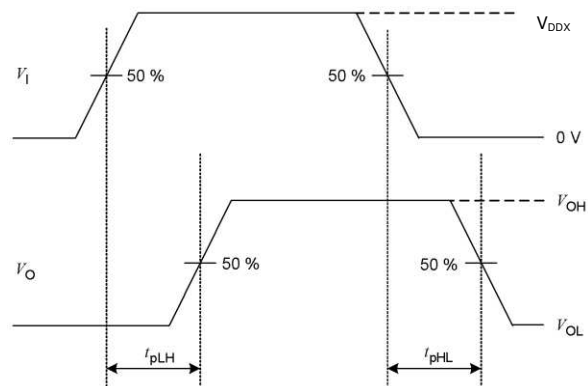


Figure16. Propagation delay time waveform measurement

APPLICATIONS INFORMATION

OVERVIEW

The $\pi 1xxxx$ are 2PaiSemi digital isolators product family based on 2PaiSEMI unique **iDivider** technology. Intelligent voltage **Divider** technology (**iDivider** technology) is a new generation digital isolator technology invented by 2PaiSEMI. It uses the principle of capacitor voltage divider to transmit signal directly cross the isolator capacitor without signal modulation and demodulation. Compare to the traditional Opto-coupler technology, icoupler technology, OOK technology, **iDivider** is a more essential and concise isolation signal transmit technology which leads to greatly simplification on circuit design and therefore significantly improves device performance, such as lower power consumption, faster speed, enhanced anti-interference ability, lower noise.

By using matured standard semiconductor CMOS technology and the innovative **iDivider** design, these isolation components provide outstanding performance characteristics and reliability superior to alternatives such as optocoupler devices and other integrated isolators. The $\pi 1xxxx$ isolator data channels are independent and are available in a variety of configurations with a withstand voltage rating of 1.5 kV rms to 6.0 kV rms and the data rate from DC up to 600Mbps (see the Ordering Guide).

The $\pi 120Uxx/\pi 121Uxx/\pi 122Uxx$ are the outstanding 150Kbps dual-channel digital isolators with the enhanced ESD capability. the devices transmit data across an isolation barrier by layers of silicon dioxide isolation.

The devices operate with the supply voltage on either side ranging from 3.0 V to 5.5 V, offering voltage translation of 3.3 V and 5 V logic.

The $\pi 120Uxx/\pi 121Uxx/\pi 122Uxx$ have very low propagation delay and high speed. The input/output design techniques allow logic and supply voltages over a wide range from 3.0 V to 5.5 V, offering voltage translation of 3.3 V and 5 V logic. The architecture is designed for high common-mode transient immunity and high immunity to electrical noise and magnetic interference.

See the Ordering Guide for the model numbers that have the fail-safe output state of low or high.

PCB LAYOUT

The low-ESR ceramic bypass capacitors must be connected between V_{DD1} and GND_1 and between V_{DD2} and GND_2 . The bypass capacitors are placed on the PCB as close to the isolator device as possible. The recommended bypass capacitor value is between 0.1 μF and 10 μF . To enhance the robustness of a design,

the user may also include resistors (50–300 Ω) in series with the inputs and outputs if the system is excessively noisy.

Avoid reducing the isolation capability, Keep the space underneath the isolator device free from metal such as planes, pads, traces and vias.

To minimize the impedance of the signal return loop, keep the solid ground plane directly underneath the high-speed signal path, the closer the better. The return path will couple between the nearest ground plane to the signal path. Keep suitable trace width for controlled impedance transmission lines interconnect.

To reduce the rise time degradation, keep the length of input/output signal traces as short as possible, and route low inductance loop for the signal path and It's return path.

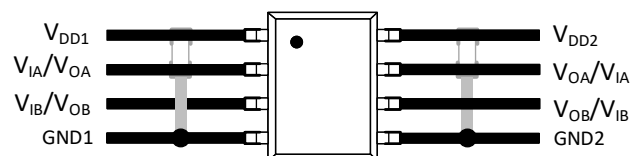


Figure17. Recommended Printed Circuit Board Layout

CMTI MEASUREMENT

To measure the Common-Mode Transient Immunity (CMTI) of $\pi 1xxxx$ isolator under specified common-mode pulse magnitude (V_{CM}) and specified slew rate of the common-mode pulse (dV_{CM}/dt) and other specified test or ambient conditions, The common-mode pulse generator (G_1) will be capable of providing fast rising and falling pulses of specified magnitude and duration of the common-mode pulse (V_{CM}) and the maximum common-mode slew rates (dV_{CM}/dt) can be applied to $\pi 1xxxx$ isolator coupler under measurement. The common-mode pulse is applied between one side ground GND_1 and the other side ground GND_2 of $\pi 1xxxx$ isolator and shall be capable of providing positive transients as well as negative transients.

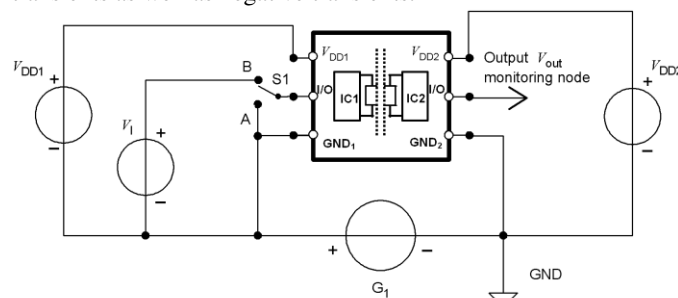
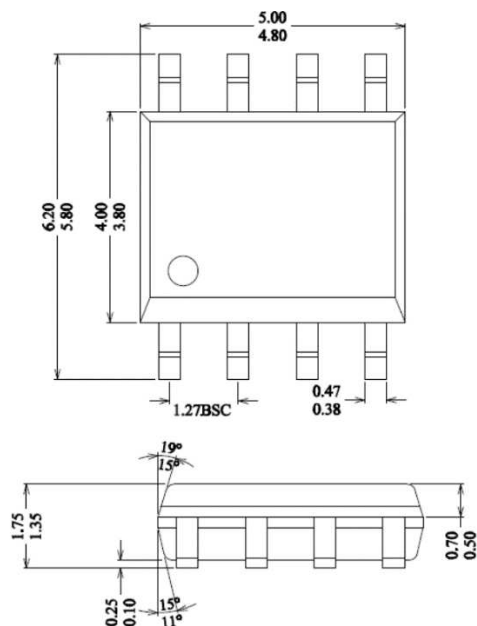


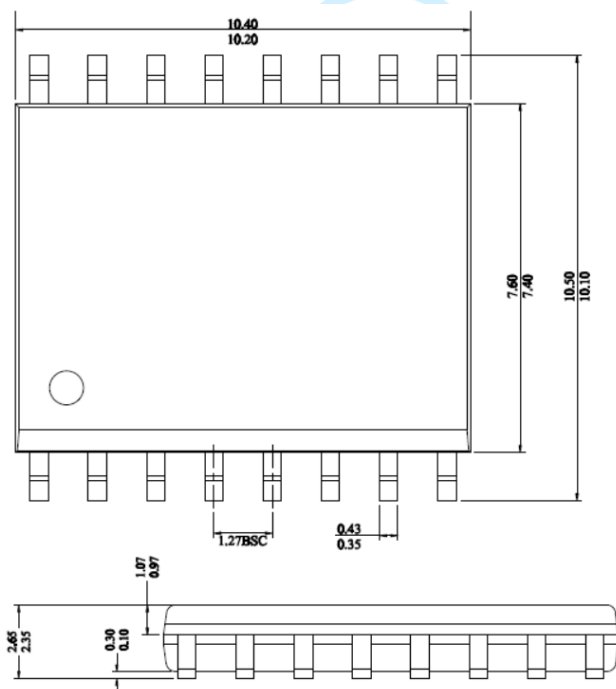
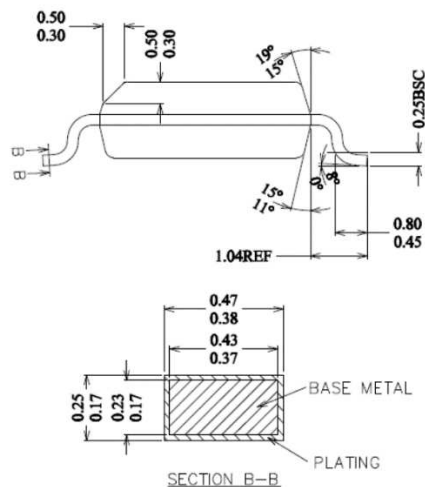
Figure18. Common-mode transient immunity (CMTI) measurement

OUTLINE DIMENSIONS



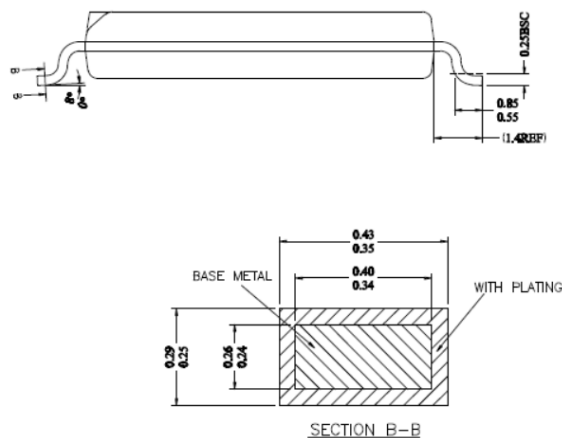
NOTES:
ALL DIMENSIONS REFER TO JEDEC STANDARD MS-012 AA
DO NOT INCLUDE MOLD FLASH OR PROTRUSION.

Figure19. 8-Lead Standard Small Outline Package [8-Lead SOIC_N]

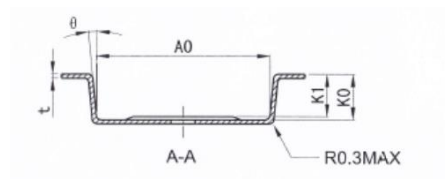


NOTES:
ALL DIMENSIONS MEET JEDEC STANDARD MS-013 AA
DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

Figure20. 16-Lead Wide Body Outline Package [16-Lead SOIC_W]



8-Lead SOIC_N

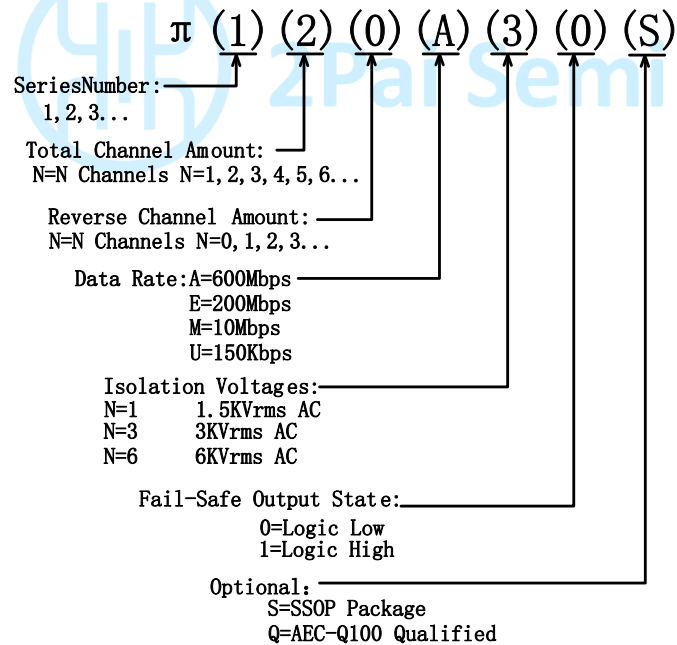


Items	Size(mm)
W	16.00±0.30
P	12.00±0.10
A0	10.90±0.10
B0	10.80±0.10
K0	3.00±0.10
t	0.30±0.05
K1	2.70±0.10
θ	5° TYP

ORDERING GUIDE

Model Name		Temperature Range	No. of Inputs, V_{DD1} Side	No. of Inputs, V_{DD2} Side	Withstand Voltage Rating (kV rms)	Fail-Safe Output State	Package Description	Package Option	Quantity
π 120U31	Pai120U31	-40°C to +125°C	2	0	3	High	8-Lead SOIC_N	S-8-N	4000 per reel
π 120U30	Pai120U30	-40°C to +125°C	2	0	3	Low	8-Lead SOIC_N	S-8-N	4000 per reel
π 121U31	Pai121U31	-40°C to +125°C	1	1	3	High	8-Lead SOIC_N	S-8-N	4000 per reel
π 121U30	Pai121U30	-40°C to +125°C	1	1	3	Low	8-Lead SOIC_N	S-8-N	4000 per reel
π 122U31	Pai122U31	-40°C to +125°C	1	1	3	High	8-Lead SOIC_N	S-8-N	4000 per reel
π 122U30	Pai122U30	-40°C to +125°C	1	1	3	Low	8-Lead SOIC_N	S-8-N	4000 per reel
π 120U61	Pai120U61	-40°C to +125°C	2	0	6	High	16-Lead SOIC_W	S-16-W	1500 per reel
π 120U60	Pai120U60	-40°C to +125°C	2	0	6	Low	16-Lead SOIC_W	S-16-W	1500 per reel
π 121U61	Pai121U61	-40°C to +125°C	1	1	6	High	16-Lead SOIC_W	S-16-W	1500 per reel
π 121U60	Pai121U60	-40°C to +125°C	1	1	6	Low	16-Lead SOIC_W	S-16-W	1500 per reel
π 122U61	Pai122U61	-40°C to +125°C	1	1	6	High	16-Lead SOIC_W	S-16-W	1500 per reel
π 122U60	Pai122U60	-40°C to +125°C	1	1	6	Low	16-Lead SOIC_W	S-16-W	1500 per reel

PART NUMBER NAMED RULE



Notes:

Pai12xxxx equals to π 12xxxx in the customer BOM

REVISION HISTORY

Revision	Updated	Date	Page	Change Record
1	Jason	2018/09/17	All	Initial version
2	Jason	2018/11/28	P11	Changed the recommended bypass capacitor value from between 0.1 μF and 1 μF to between 0.1 μF and 10 μF .
3	Devin	2019/09/08	P1,P11,P13,P14	P1: Changed the address from 'Room 19307, Building 8, No.498, GuoShouJing Road' to 'Room 308-309, No.22, Boxia Road'; Add iDivider technology description in General Description. Changed ESD(HBM) from 7KV to 8KV. P11: Add iDivider technology description in overview. P13: Updated 16-Lead SOIC_W reel drawing. P14: Add character 'S' and 'Q' in part number named rule; Changed the SOIC_W quantity from '1000 per reel' to '1500 per reel'.

